

**IN THE TITLE OF THE INVENTION**

Please amend the Title of the Invention as indicated below:

**~~Method of Fabricating an~~ MRAM Device Including Spin Dependent Tunneling Junction Memory Cells**

**IN THE CLAIMS**

Please **Cancel Claims 1 - 11** without prejudice or disclaimer.

**REMARKS**

Claims 12 through 20 are pending in this Divisional Application. Claims 1 through 11 were canceled on the filing of this Divisional Application because they were elected without traverse for prosecution on the merits in response to a Restriction Requirement in the Parent Application, **Serial No.:** 09/514,934, HP Docket Number 10991744-1, mailed on **13 September 2001**. Claims 1 through 11 (Group I) were elected for examination on the merits and non-elected Claims 12 through 20 (Group II) were withdrawn from consideration.

Applicant has amended the Title of the Invention to accurately reflect the subject matter of the divisional application as being drawn to an apparatus instead of a method. Therefore, the Title of the Invention as amended herein is: **"MRAM Device Including Spin Dependent Tunneling Junction Memory Cells"**

Accordingly, Claims 12 through 20 are submitted herewith for examination on the merits in this Divisional Application.

**CONCLUSION**

Based on the foregoing, the Applicant considers each of the claims presently in the application to be distinct over the prior art of record and therefore in condition for allowance. Accordingly, the Applicant respectfully requests that the claims be allowed and the issuance of a Notice of Allowance such that the present application may timely issue as a U.S. patent.

Respectfully submitted,

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By: 

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